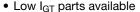
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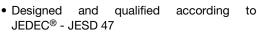
Thyristor High Voltage, Phase Control SCR, 40 A



PRIMARY CHARACTERISTICS					
I _{T(AV)} 35 A					
V _{DRM} /V _{RRM}	1200 V				
V_{TM}	1.45 V				
I _{GT}	150 mA				
T_J	-40 °C to +125 °C				
Package	TO-247AD 3L				
Circuit configuration	Single SCR				

FEATURES







Flexible solution for reliable AC power rectification

- rectification

 Easy control peak current at charger power up to reduce
- passive / electromechanical componentsMaterial categorization: for definitions of compliance
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

DESCRIPTION

The VS-40TPS12.. high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications.

AEC-Q101 qualified P/N available (VS-40TPS12LHM3, VS-40TPS12ALHM3).

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I _{T(AV)}	Sinusoidal waveform	35	A		
I _{RMS}		55	^		
V _{RRM} /V _{DRM}		1200	V		
I _{TSM}		600	Α		
V _T	40 A, T _J = 25 °C	1.45	V		
dv/dt		1000	V/µs		
di/dt		100	A/µs		
TJ		-40 to +125	°C		

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA
VS-40TPS12AL-M3	1200	1300	10
VS-40TPS12L-M3	1200	1300] 10



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ABSOLUTE MAXIMUM RATINGS	}				
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 79 °C, 180° conduction half sine wave	Э	35	
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}			55	А
Maximum peak, one-cycle		10 ms sine pulse, rated V _{RRM} applied		500	
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied	ladial	600	
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	Initial $T_{.1} = T_{.1} \text{ max.}$	1250	A ² s
Maximum I-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	ij – ijiliax.	1760	A ² S
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	1	17 600	A²√s
Low level value of threshold voltage	V _{T(TO)1}		1.02	V	
High level value of threshold voltage	V _{T(TO)2}	T 105 °C	1.23	v	
Low level value of on-state slope resistance	r _{t1}	T _J = 125 °C	9.74	m0	
High level value of on-state slope resistance	r _{t2}		7.50	mΩ	
Maximum peak on-state voltage	V_{TM}	110 A, T _J = 25 °C		1.85	V
Maximum rate of rise of turned-on current	di/dt	T _J = 25 °C		100	A/µs
Maximum holding current	I _H	Anode supply = 6 V , resistive load, initial T_J	= 1 A, I _T = 25 °C	300	
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T _J = 25 °C		350	т Л
Marrian was a sound alive at leading a summer		T _J = 25 °C		0.5	mA
Maximum reverse and direct leakage current	I _{RRM/} I _{DRM}	$V_R = \text{rated } V_{RRM}/V_{DR}$	RM	10	1
Maximum rate of rise of off-state voltage 40TPS12A	dv/dt	T_J = T_J maximum, linear to 80 % V_{DRM} , R_g - k = 100 Ω		500	V/uo
Maximum rate of rise of off-state voltage 40TPS12	αν/ατ			1000	− V/µs

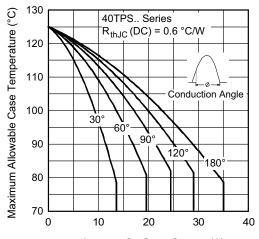
TRIGGERING					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum peak gate power	P _{GM}			10	W
Maximum average gate power	P _{G(AV)}			2.5	VV
Maximum peak gate current	I _{GM}			2.5	Α
Maximum peak negative gate voltage	-V _{GM}			10	V
		T _J = -40 °C	Anada sunah. CV	2.0	
Maximum required DC gate voltage to trigger	V_{GT}	T _J = 25 °C	Anode supply = 6 V	1.7	V
		T _J = 125 °C	Tesistive load	1.3	
	I _{GT}	T _J = -40 °C	Anode supply = 6 V resistive load	200	
Maximum required DC gate current to trigger		T _J = 25 °C		150	mA
Maximum required DC gate current to trigger		T _J = 125 °C		80	
		$T_J = 25$ °C, for 40TPS12A		40	İ
Maximum DC gate voltage not to trigger for 40TPS12	V_{GD}	T _J = 125 °C, V _{DRM} = rated value		0.25	٧
Maximum DC gate current not to trigger for 40TPS12	I _{GD}			6	mA
Maximum DC gate voltage not to trigger for 40TPS12A	V_{GD}	T _J = 125 °C, V _{DRM} = rated value		0.15	V
Maximum DC gate current not to trigger for 40TPS12A	I _{GD}			1	mA



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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +125	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.6	°C/W		
Maximum thermal resistance, junction to ambient	R_{thJA}	DC operation	40			
Maximum thermal resistance, case to heat sink	R _{thCS}	Mounting surface, smooth and greased	0.25			
Approximate weight			6	g		
Approximate weight			0.21	OZ.		
Mounting torque minimum			6 (5)	kgf · cm		
maximum			12 (10)	(lbf · in)		
Marking davise		Consectula TO 247AD 21	40TPS1	2AL		
Marking device		Case style TO-247AD 3L	40TPS12L			



Average On-State Current (A) Fig. 1 - Current Rating Characteristics

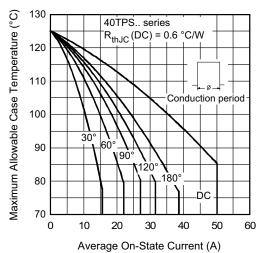


Fig. 2 - Current Rating Characteristics

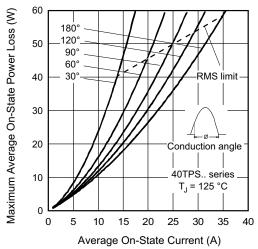


Fig. 3 - On-State Power Loss Characteristics

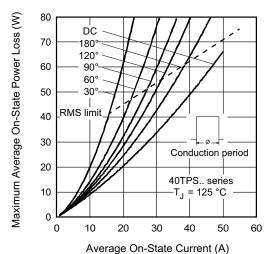


Fig. 4 - On-State Power Loss Characteristics

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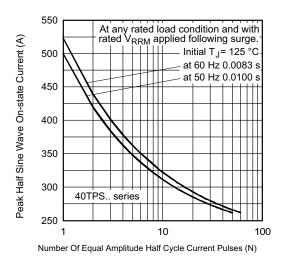


Fig. 5 - Maximum Non-Repetitive Surge Current

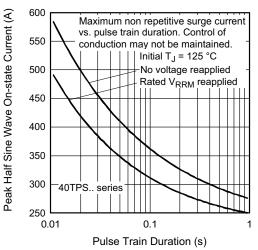
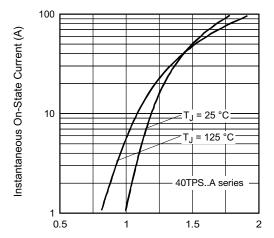
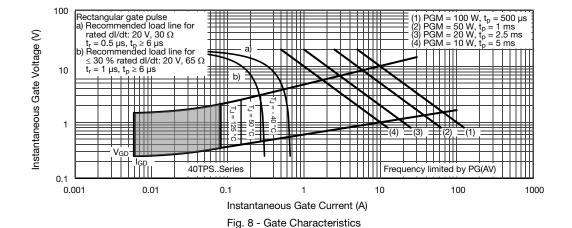


Fig. 6 - Maximum Non-Repetitive Surge Current

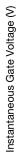


Instantaneous On-State Voltage (V)
Fig. 7 - On-State Voltage Drop Characteristics



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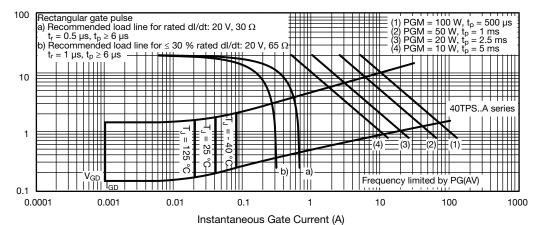


Fig. 9 - Gate Characteristics

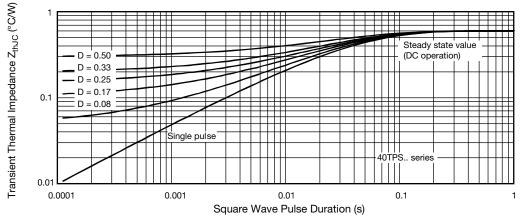
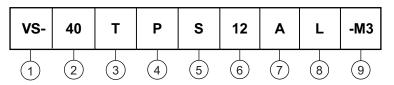


Fig. 10 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (40 = 40 A)

3 - Circuit configuration:

T = thyristor

4 - Package:

P = TO-247

5 - Type of silicon:

S = standard recovery rectifier

- Voltage ratings — 12 = 1200 V

A = Low lgt selection 40 mA maximum

• None = standard lgt selection

8 - L = long leads

9 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-40TPS12AL-M3	25	500	Antistatic plastic tubes		
VS-40TPS12L-M3	25	500	Antistatic plastic tubes		

LINKS TO RELATED DOCUMENTS				
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626		
Part marking information TO-247AD 3L <u>www.vishay.com/doc?95007</u>				



Vishay Semiconductors

TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

MILLIMETERS INCHES					
SYMBOL	IVIILLIIV	IETEKS	INCHES		NOTES
01202	MIN.	MAX.	MIN.	MAX.	
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
OTIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØК	0.2	254	0.0)10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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